



Main Features:

- Frequency Range: 12 to 18 GHz.
- Typical values: NF 2 dB, Gain 50 dB
- RF connectors (I/O): SMA mm Female
- Solder filtered pins for DC connection
- Several mounting options
- Gold plated compact aluminum housing
- Hi-reliability and dedicated screening/ environmental tests available under request

ERZ-LNA-1200-1800-50-2

The ERZ-LNA-1200-1800-50-2 is a Ku Band Low Noise Amplifier providing a Noise Figure of 2 dB and gain of 50 dB. The compact size and modularity makes it ideal for a wide range of applications.

Typical applications:

- Industrial / Laboratory
- Satcom / Telecom
- Space / Aerospace

Performance

Parameter	Value			Units
	Min	Typ	Max	
Frequency (GHz)	12	-	18	GHz
Small Signal Gain (dB)	46	50	55	dBm
Gain Flatness (dB)	-	±2	-	dB
Noise Figure (dB)	1.5	-	2.5	dB
Output Power @P1dB (dBm)	-	18	-	dBm
Output VSWR	-	1.7:1	2.2:1	-
Input VSWR	-	1.6:1	1.8:1	-
Power Consumption (W)	-	7.8	-	W
DC Voltage (V)	9	12	15	V

Specifications at a case temperature of 25°C at 12V.

Noise Figure

Figure 1 shows noise figure (NF) measurement as a function of frequency at room temperature (25°C).

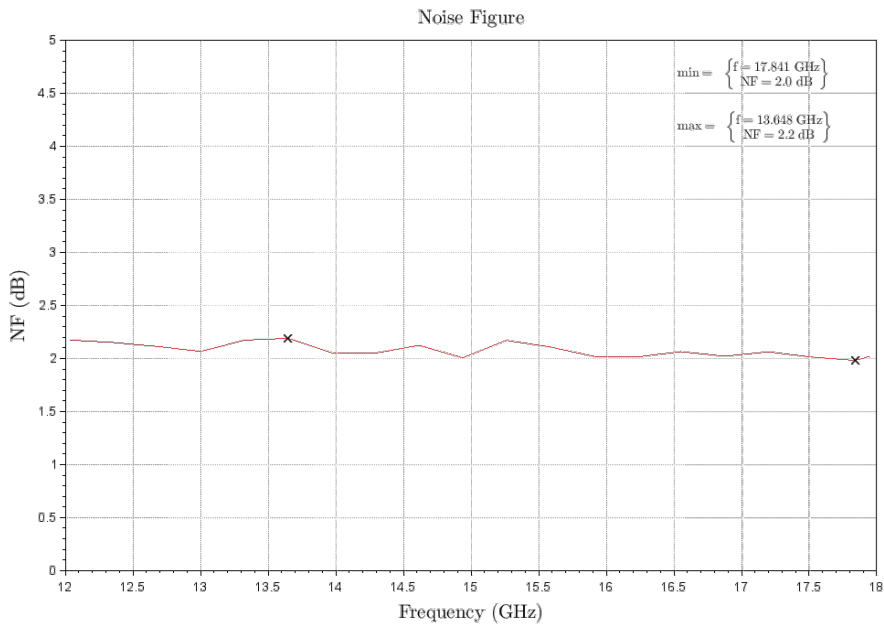


Figure 1: ERZ-LNA-1200-1800-50-2 Psat

Small Signal Gain

Figure 2 shows the small signal gain measurement as a function of frequency.

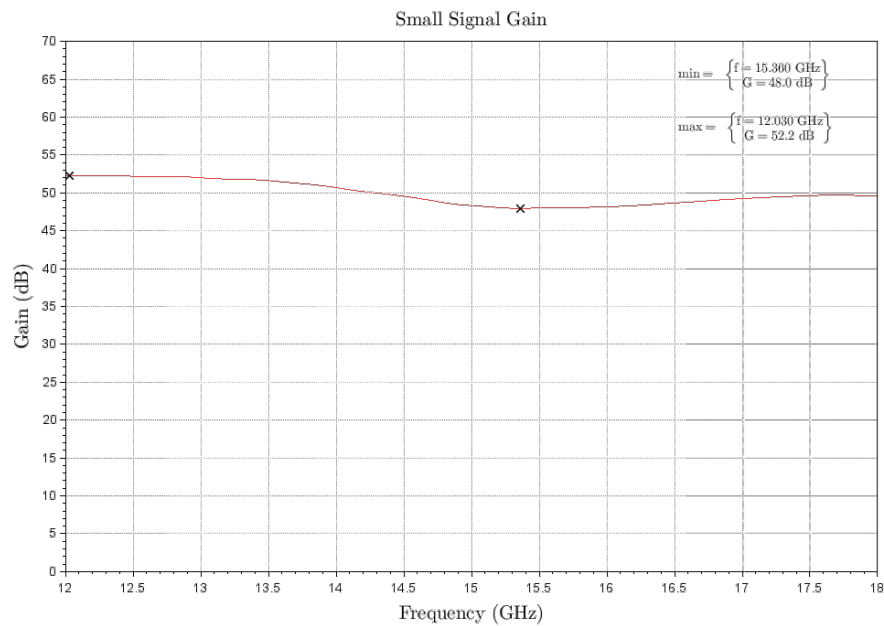


Figure 2: ERZ-LNA-1200-1800-50-2 Small Signal Gain over frequency

Input and Output Matching

Figure 3 shows input (S11) and output (S22) VSWR as a function of frequency at room temperature (25°C).

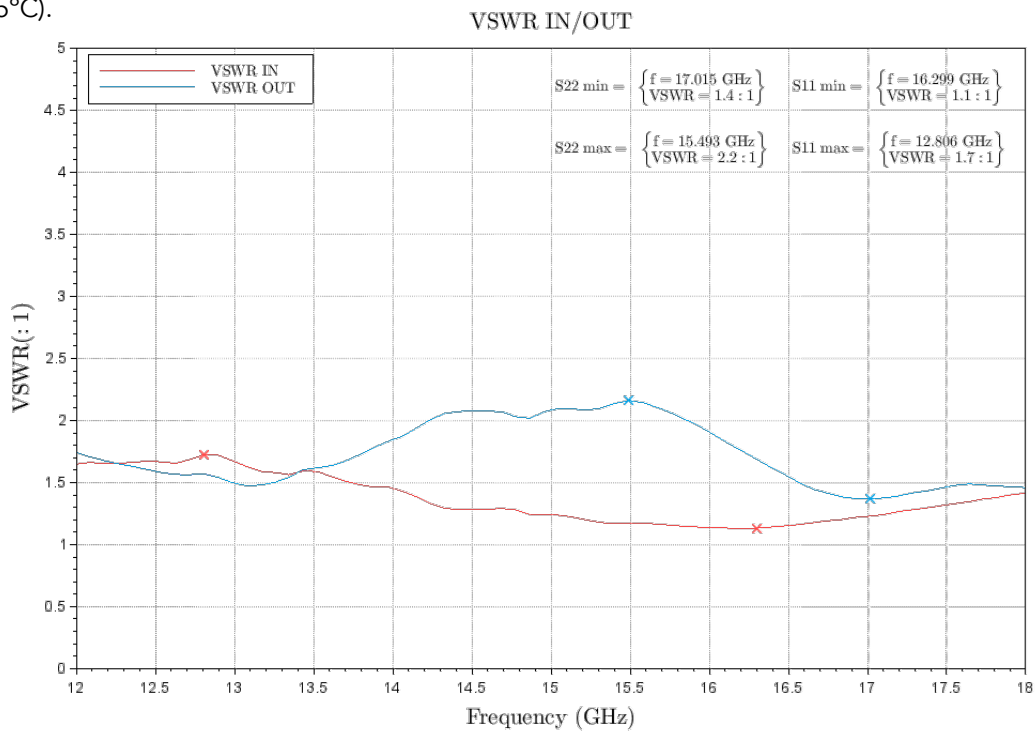


Figure 3: ERZ-LNA-1200-1800-50-2 Input and Output matching

Measurements Conditions

All measurements provided in this report were performed at the following conditions:

Condition	Value
Temperature (DUT ON)	25°C ± 1°C
Humidity	44% ± 10%
DUT Warm up time	30 min
DUT minimum operation time	12 hours
Test equipment warm up time	2 hours
Additional temperature cycles in climatic chamber (DUT OFF)	-40°C to 85°C

Absolute Maximum Ratings

Condition	Value
DC Voltage	12 +/-4 VDC
Maximum Input Power (CW)	10 dBm
Operation temperature (at case)	-40 to 85°C
Storage temperature	-55 to 125°C

- Stress above these ratings may cause permanent damage to the device.
- It is final user responsibility to maintain the amplifier within the specified ranges.

Environmental Specifications (By Design)

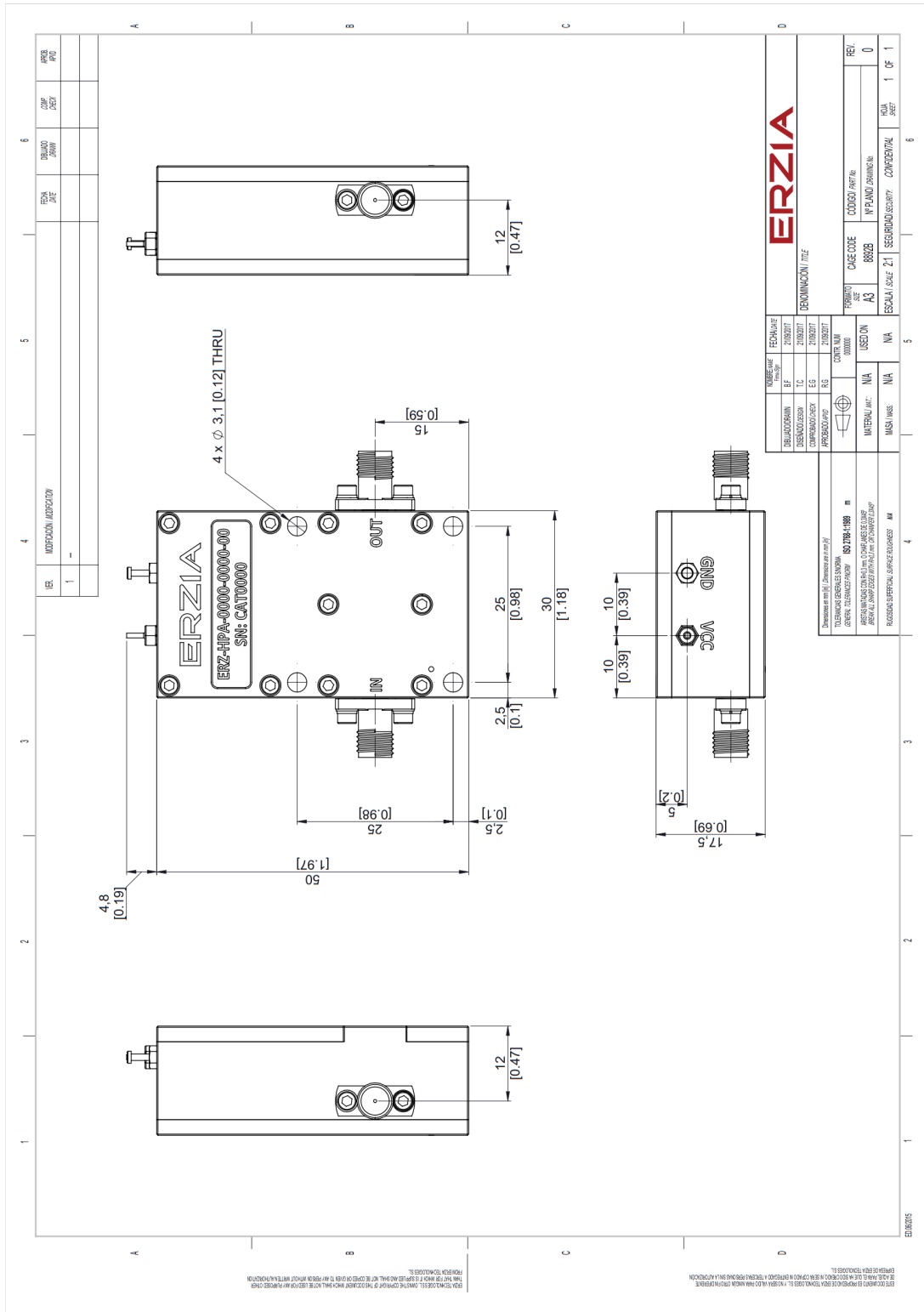
Operating Temperature:	-40 to +85 °C	(MIL-STD-810F, method 520.2)
Storage Temperature:	-55 to 125 °C	(MIL-STD-810F, method 520.2)
Vibration:	8g rms	(MIL-STD-810F, method 514.5)
Shock:	20g,11ms,saw-tooth	(MIL-STD-810F, method 516.5)
Acceleration:	15g	(MIL-STD-810F, method 513.5)

RoHS & REACH Compliance

This part is compliant with EU 2011/65/UE RoHS (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) and REACH (Registration, Evaluation, Authorization and restriction of Chemical substances) directives.



Mechanics and Housing



Documentation and Test Reports

All modules are at least delivered with: Electrical Test Report, Certificate of Conformance, Certificate of Acceptance and Origin. Optionally, units can be environmentally tested (temperature, vibration...).

Option (HS): Heat Sink

A heat sink (HS) can be provided to allow the operation of Power Amplifiers. Please note that most power amplifiers need heat sink or appropriate heat dissipation strategy.

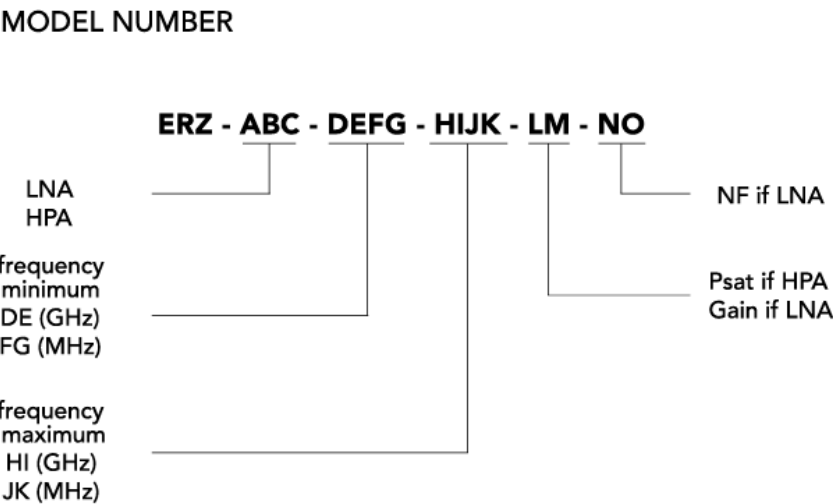
Space / Hi-Rel Usage

Most of ERZIA’s products are based on rad-hard technologies and can be manufactured and integrated according to MIL / ECSS or specific hi-rel standard-screening for space, aeronautics, or specific hi-reliability usage.

Customization and Extended Performances

ERZIA can fully design or adapt one of the existing RF amplifiers designs according to your specifications. Please contact us for additional information.

Model Number Codification



ERZIA

20260818_rev1.1

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